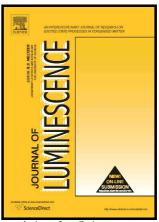
## Author's Accepted Manuscript

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### **ACCEPTED MANUSCRIPT**

# Plasmon multiwavelength-sensitized luminescence enhancement of highly transparent Ag/YVO<sub>4</sub>:Eu<sup>3+</sup>/PMMA film

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